

**XPT™ 650V IGBT**  
**GenX3™**
**IXYA20N65B3**  
**IXYP20N65B3**  
**IXYH20N65B3**

 Extreme Light Punch Through  
 IGBT for 5-30kHz Switching


| Symbol                        | Test Conditions   | Maximum Ratings                          |                  |
|-------------------------------|---|--|------------------|
| $V_{CES}$                     | $T_J = 25^\circ\text{C}$ to $175^\circ\text{C}$   | 650                                      | V                |
| $V_{CGR}$                     | $T_J = 25^\circ\text{C}$ to $175^\circ\text{C}$ , $R_{GE} = 1\text{M}\Omega$                                    | 650                                      | V                |
| $V_{GES}$                     | Continuous  | $\pm 20$                                 | V                |
| $V_{GEM}$                     | Transient   | $\pm 30$                                 | V                |
| $I_{C25}$                     | $T_C = 25^\circ\text{C}$  | 58                                       | A                |
| $I_{C110}$                    | $T_C = 110^\circ\text{C}$   | 20                                       | A                |
| $I_{CM}$                      | $T_C = 25^\circ\text{C}$ , 1ms  | 108                                      | A                |
| $I_A$                         | $T_C = 25^\circ\text{C}$  | 10                                       | A                |
| $E_{AS}$                      | $T_C = 25^\circ\text{C}$  | 200                                      | mJ               |
| <b>SSOA</b><br><b>(RBSOA)</b> | $V_{GE} = 15\text{V}$ , $T_{VJ} = 150^\circ\text{C}$ , $R_G = 20\Omega$<br>Clamped Inductive Load               | $I_{CM} = 40$<br>@ $V_{CE} \leq V_{CES}$ | A                |
| $t_{sc}$<br><b>(SCSOA)</b>    | $V_{GE} = 15\text{V}$ , $V_{CE} = 360\text{V}$ , $T_J = 150^\circ\text{C}$<br>$R_G = 82\Omega$ , Non Repetitive | 5  | $\mu\text{s}$    |
| $P_C$                         | $T_C = 25^\circ\text{C}$  | 230                                      | W                |
| $T_J$                         |   | -55 ... +175                             | $^\circ\text{C}$ |
| $T_{JM}$                      |   | 175                                      | $^\circ\text{C}$ |
| $T_{stg}$                     |   | -55 ... +175                             | $^\circ\text{C}$ |
| $T_L$                         | Maximum Lead Temperature for Soldering  | 300                                      | $^\circ\text{C}$ |
| $T_{SOLD}$                    | 1.6 mm (0.062in.) from Case for 10s   | 260                                      | $^\circ\text{C}$ |
| $F_C$                         | Mounting Force (TO-263)   | 10..65 / 2.2..14.6                       | N/lb             |
| $M_d$                         | Mounting Torque (TO-247 & TO-220)   | 1.13 / 10                                | Nm/lb.in         |
| <b>Weight</b>                 | TO-263  | 2.5                                      | g                |
|                               | TO-220  | 3.0                                      | g                |
|                               | TO-247  | 6.0                                      | g                |

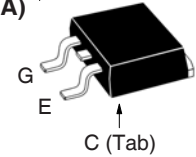
$$V_{CES} = 650\text{V}$$

$$I_{C110} = 20\text{A}$$

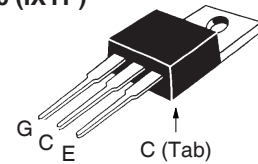
$$V_{CE(sat)} \leq 2.10\text{V}$$

$$t_{fi(\text{typ})} = 87\text{ns}$$

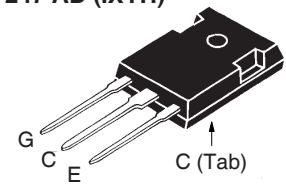
TO-263 (IXYA)



TO-220 (IXYP)



TO-247 AD (IXYH)


 G = Gate      C = Collector  
 E = Emitter    Tab = Collector

**Features**

- Optimized for 5-30kHz Switching
- Square RBSOA
- Avalanche Rated
- Short Circuit Capability
- International Standard Packages

**Advantages**

- High Power Density
- Extremely Rugged
- Low Gate Drive Requirement

**Applications**

- Power Inverters
- UPS
- Motor Drives
- SMPS
- PFC Circuits
- Battery Chargers
- Welding Machines
- Lamp Ballasts

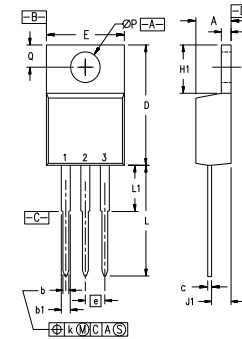
| Symbol        | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)      | Characteristic Values |              |                                       |
|---------------|--|-----------------------|--------------|---------------------------------------|
|               |  | Min.                  | Typ.         | Max.                                  |
| $BV_{CES}$    | $I_C = 250\mu\text{A}$ , $V_{GE} = 0\text{V}$                                    | 650                   |              | V                                     |
| $V_{GE(th)}$  | $I_C = 250\mu\text{A}$ , $V_{CE} = V_{GE}$                                       | 3.5                   |              | 6.0 V                                 |
| $I_{CES}$     | $V_{CE} = V_{CES}$ , $V_{GE} = 0\text{V}$<br>$T_J = 150^\circ\text{C}$           |                       |              | 10 $\mu\text{A}$<br>150 $\mu\text{A}$ |
| $I_{GES}$     | $V_{CE} = 0\text{V}$ , $V_{GE} = \pm 20\text{V}$                                 |                       |              | $\pm 100$ nA                          |
| $V_{CE(sat)}$ | $I_C = 20\text{A}$ , $V_{GE} = 15\text{V}$ , Note 1<br>$T_J = 150^\circ\text{C}$ |                       | 1.77<br>2.05 | V<br>V                                |

| Symbol Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified) |  | Characteristic Values |      |                         |
|--|--|-----------------------|------|-------------------------|
|  |  | Min.                  | Typ. | Max.                    |
| $g_{fs}$   | $I_C = 20\text{A}, V_{CE} = 10\text{V}$ , Note 1   | 8.5                   | 14   | S                       |
| $C_{ies}$  | $V_{CE} = 25\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$   |                       | 826  | pF                      |
| $C_{oes}$  |  |                       | 66   | pF                      |
| $C_{res}$  |  |                       | 19   | pF                      |
| $Q_{g(on)}$  | $I_C = 20\text{A}, V_{GE} = 15\text{V}, V_{CE} = 0.5 \cdot V_{CES}$  |                       | 29   | nC                      |
| $Q_{ge}$   |  |                       | 6    | nC                      |
| $Q_{gc}$   |  |                       | 14   | nC                      |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b><br>$I_C = 20\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 400\text{V}, R_G = 20\Omega$<br>Note 2  |                       | 12   | ns                      |
| $t_{ri}$   |  |                       | 25   | ns                      |
| $E_{on}$   |  |                       | 0.50 | mJ                      |
| $t_{d(off)}$   |  |                       | 103  | ns                      |
| $t_{fi}$   |  |                       | 87   | ns                      |
| $E_{off}$  |  | 0.45                  | 0.70 | mJ                      |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 150^\circ\text{C}</math></b><br>$I_C = 20\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 400\text{V}, R_G = 20\Omega$<br>Note 2 |                       | 13   | ns                      |
| $t_{ri}$   |  |                       | 26   | ns                      |
| $E_{on}$   |  |                       | 0.93 | mJ                      |
| $t_{d(off)}$   |  |                       | 124  | ns                      |
| $t_{fi}$   |  |                       | 147  | ns                      |
| $E_{off}$  |  | 0.76                  | mJ   |                         |
| $R_{thJC}$   |  |                       |      | 0.65 $^\circ\text{C/W}$ |
| $R_{thCS}$   | TO-220   |                       | 0.50 | $^\circ\text{C/W}$      |
| $R_{thCS}$   | TO-247   |                       | 0.21 | $^\circ\text{C/W}$      |

**Notes:**

1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .
2. Switching times & energy losses may increase for higher  $V_{CE}$  (clamp),  $T_J$  or  $R_G$ .

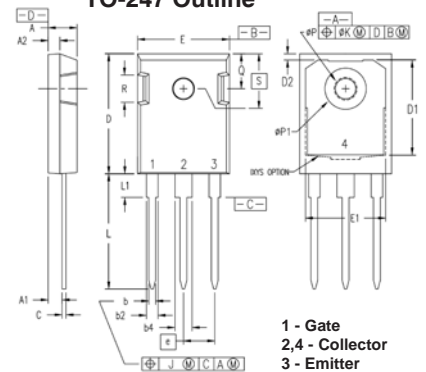
**TO-220 Outline**



Pins: 1 - Gate  
2 - Collector  
3 - Emitter

| SYM | INCHES   |      | MILLIMETERS |       |
|-----|----------|------|-------------|-------|
|     | MIN      | MAX  | MIN         | MAX   |
| A   | .170     | .190 | 4.32        | 4.83  |
| b   | .025     | .040 | 0.64        | 1.02  |
| b1  | .045     | .065 | 1.15        | 1.65  |
| c   | .014     | .022 | 0.35        | 0.56  |
| D   | .580     | .630 | 14.73       | 16.00 |
| E   | .390     | .420 | 9.91        | 10.66 |
| e   | .100 BSC |      | 2.54 BSC    |       |
| F   | .045     | .055 | 1.14        | 1.40  |
| H1  | .230     | .270 | 5.85        | 6.85  |
| J1  | .090     | .110 | 2.29        | 2.79  |
| k   | 0        | .015 | 0           | 0.38  |
| L   | .500     | .550 | 12.70       | 13.97 |
| L1  | .110     | .230 | 2.79        | 5.84  |
| ØP  | .139     | .161 | 3.53        | 4.08  |
| Q   | .100     | .125 | 2.54        | 3.18  |

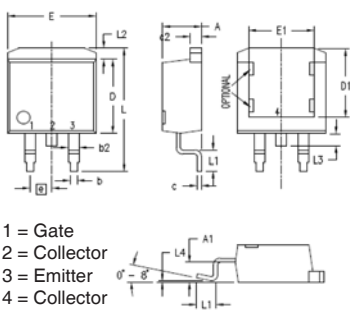
**TO-247 Outline**



1 - Gate  
2,4 - Collector  
3 - Emitter

| Dim. | Millimeter |       | Inches    |       |
|------|------------|-------|-----------|-------|
|      | min        | max   | min       | max   |
| A    | 4.70       | 5.30  | 0.185     | 0.209 |
| A1   | 2.21       | 2.59  | 0.087     | 0.102 |
| A2   | 1.50       | 2.49  | 0.059     | 0.098 |
| b    | 0.99       | 1.40  | 0.039     | 0.055 |
| b2   | 1.65       | 2.39  | 0.065     | 0.094 |
| b4   | 2.59       | 3.43  | 0.102     | 0.135 |
| c    | 0.38       | 0.89  | 0.015     | 0.035 |
| D    | 20.79      | 21.45 | 0.819     | 0.845 |
| D1   | 13.07      | -     | 0.515     | -     |
| D2   | 0.51       | 1.35  | 0.020     | 0.053 |
| E    | 15.48      | 16.24 | 0.610     | 0.640 |
| E1   | 13.45      | -     | 0.53      | -     |
| E2   | 4.31       | 5.48  | 0.170     | 0.216 |
| e    | 5.45 BSC   |       | 0.215 BSC |       |
| L    | 19.80      | 20.30 | 0.778     | 0.800 |
| L1   | -          | 4.49  | -         | 0.177 |
| ØP   | 3.55       | 3.65  | 0.140     | 0.144 |
| ØP1  | -          | 7.39  | -         | 0.290 |
| Q    | 5.38       | 6.19  | 0.212     | 0.244 |
| S    | 6.14 BSC   |       | 0.242 BSC |       |

**TO-263 Outline**



1 = Gate  
2 = Collector  
3 = Emitter  
4 = Collector

| SYM | INCHES   |      | MILLIMETERS |       |
|-----|----------|------|-------------|-------|
|     | MIN      | MAX  | MIN         | MAX   |
| A   | .160     | .190 | 4.06        | 4.83  |
| A1  | .080     | .110 | 2.03        | 2.79  |
| b   | .020     | .039 | 0.51        | 0.99  |
| b2  | .045     | .055 | 1.14        | 1.40  |
| c   | .016     | .029 | 0.40        | 0.74  |
| c2  | .045     | .055 | 1.14        | 1.40  |
| D   | .340     | .380 | 8.64        | 9.65  |
| D1  | .315     | .350 | 8.00        | 8.89  |
| E   | .380     | .410 | 9.65        | 10.41 |
| E1  | .245     | .320 | 6.22        | 8.13  |
| e   | .100 BSC |      | 2.54 BSC    |       |
| L   | .575     | .625 | 14.61       | 15.88 |
| L1  | .090     | .110 | 2.29        | 2.79  |
| L2  | .040     | .055 | 1.02        | 1.40  |
| L3  | .050     | .070 | 1.27        | 1.78  |
| L4  | 0        | .005 | 0           | 0.13  |

**ADVANCE TECHNICAL INFORMATION**

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

|  |           |           |           |           |              |              |              |              |              |             |
|--|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: | 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
|  | 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
|  | 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$

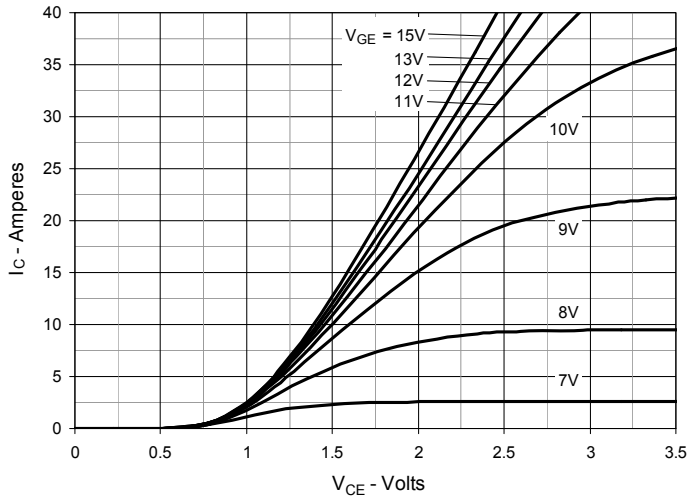


Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$

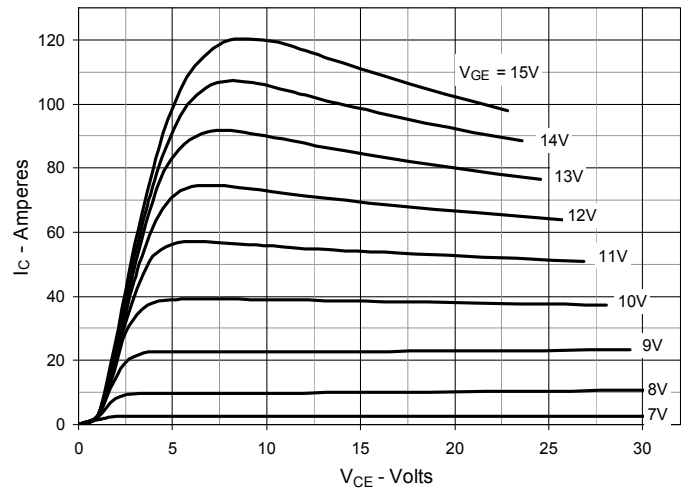


Fig. 3. Output Characteristics @  $T_J = 150^\circ\text{C}$

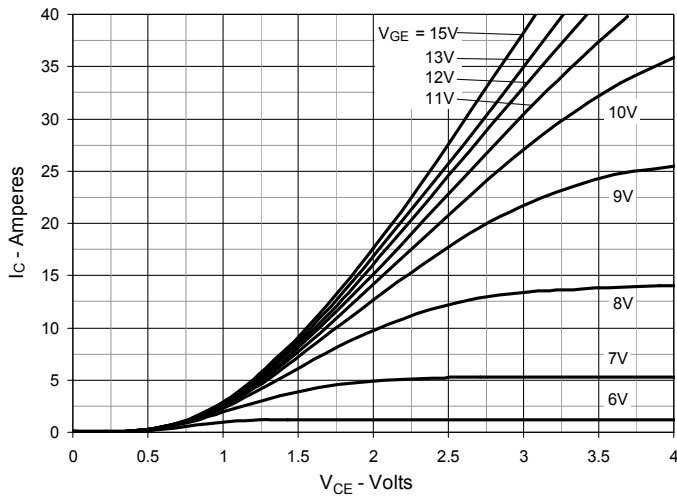


Fig. 4. Dependence of  $V_{CE(sat)}$  on Junction Temperature

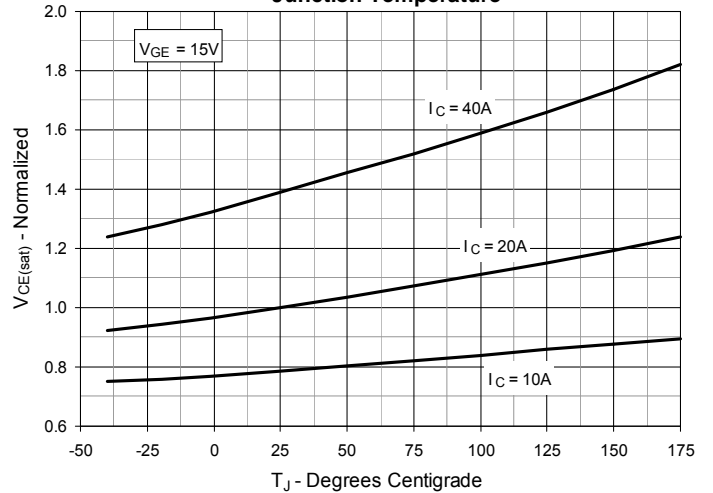


Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage

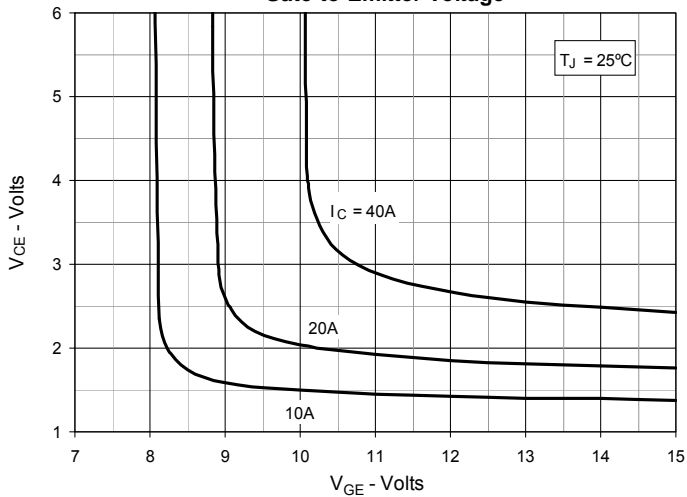


Fig. 6. Input Admittance

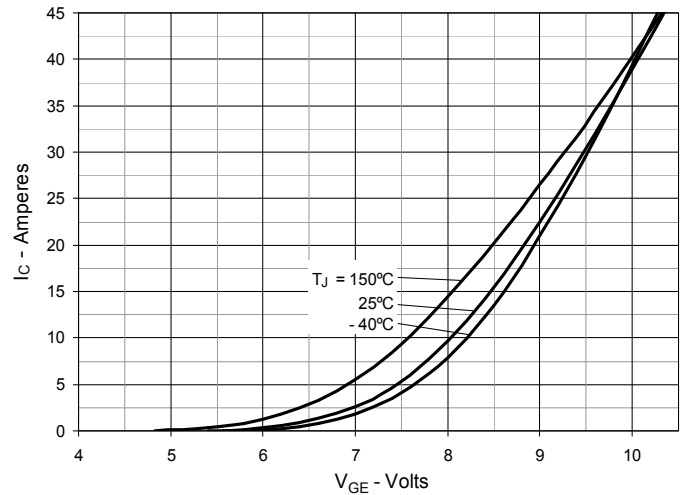


Fig. 7. Transconductance

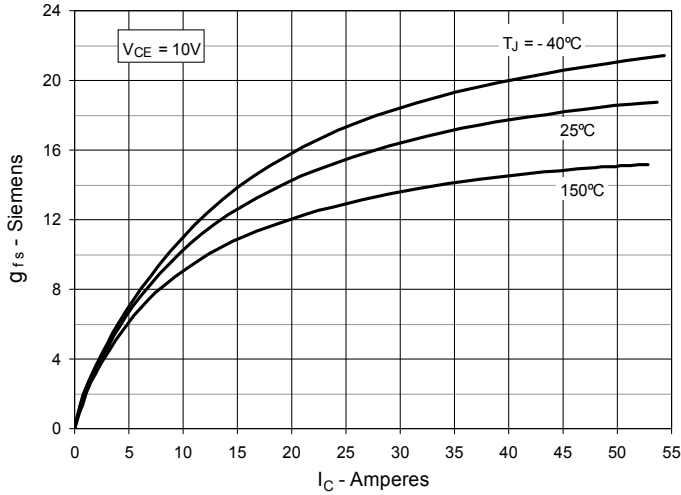


Fig. 8. Gate Charge

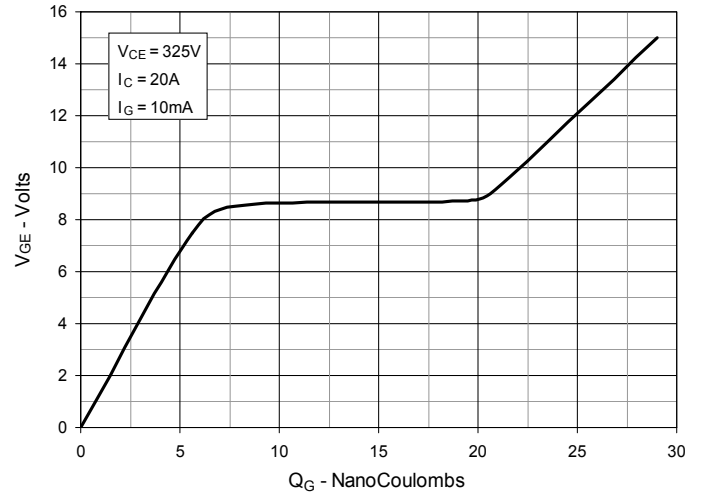


Fig. 9. Capacitance

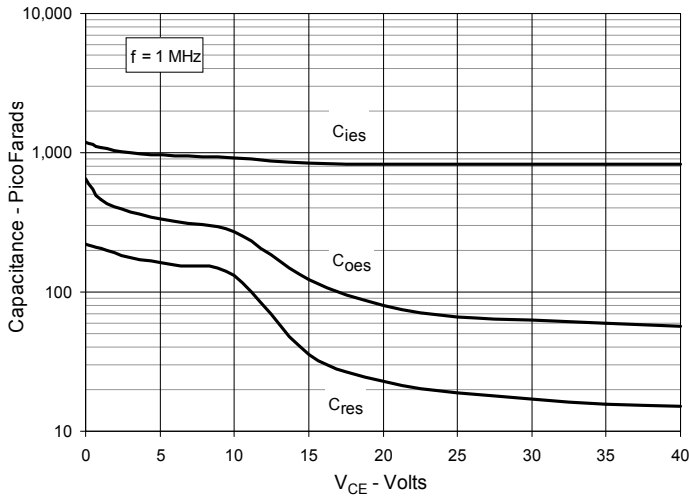


Fig. 10. Reverse-Bias Safe Operating Area

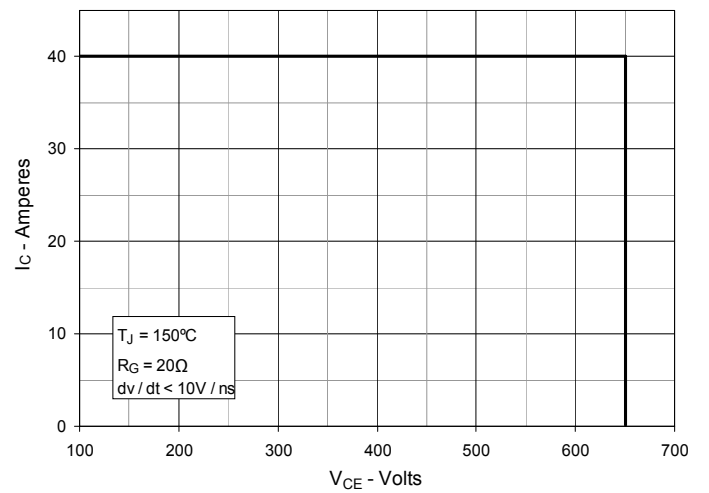


Fig. 11. Forward-Bias Safe Operating Area

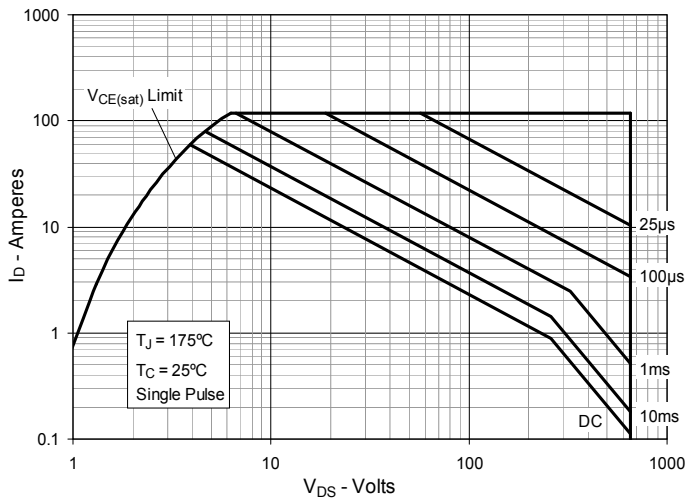
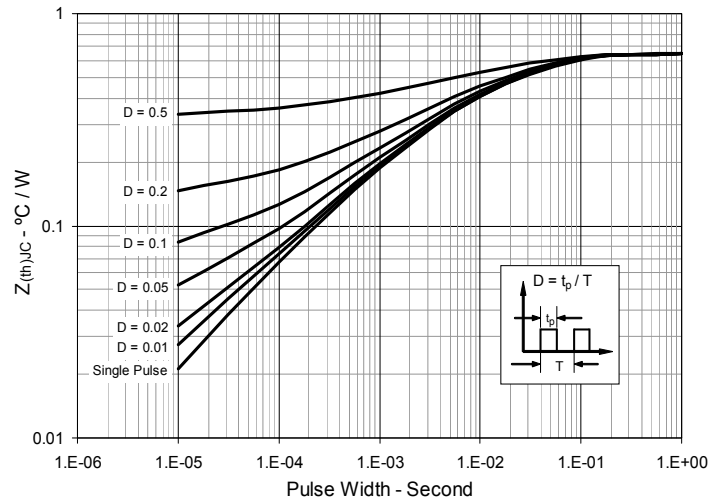
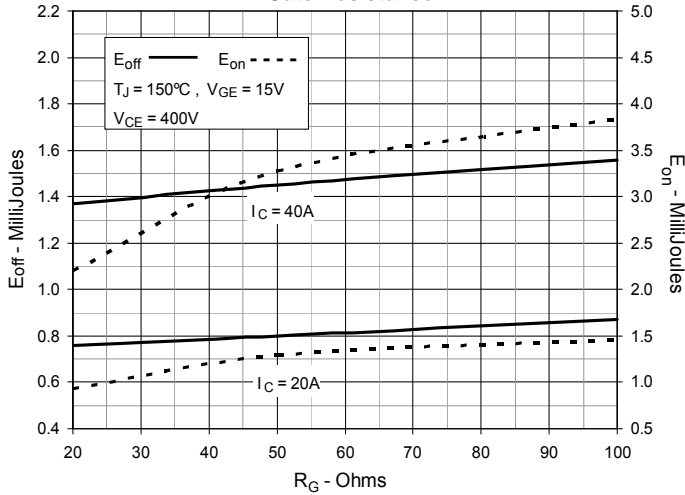


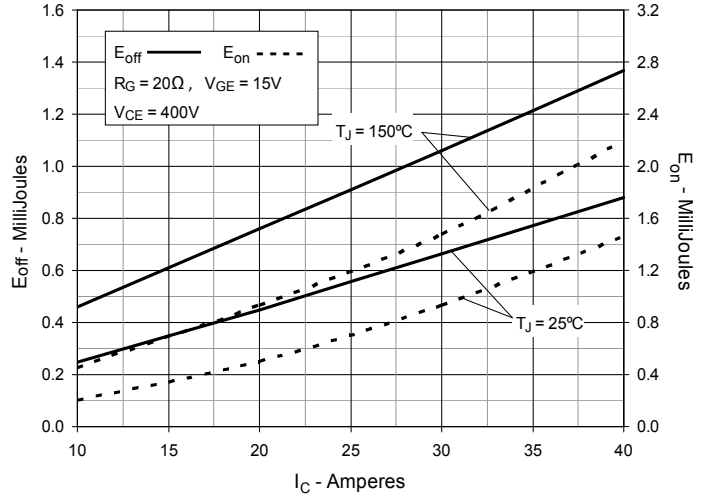
Fig. 12. Maximum Transient Thermal Impedance



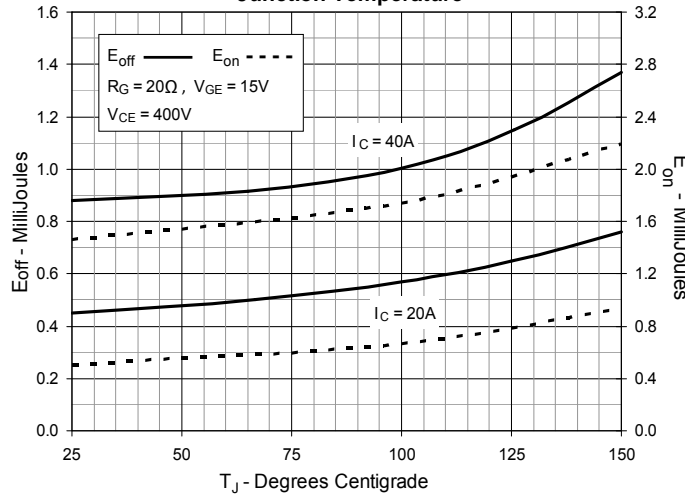
**Fig. 13. Inductive Switching Energy Loss vs. Gate Resistance**



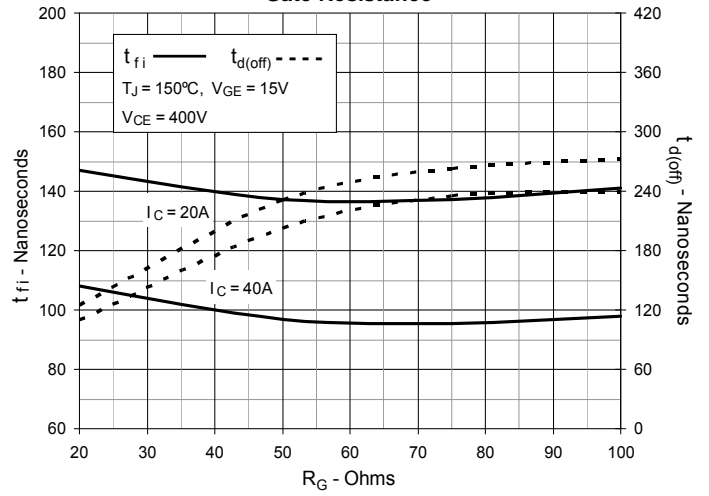
**Fig. 14. Inductive Switching Energy Loss vs. Collector Current**



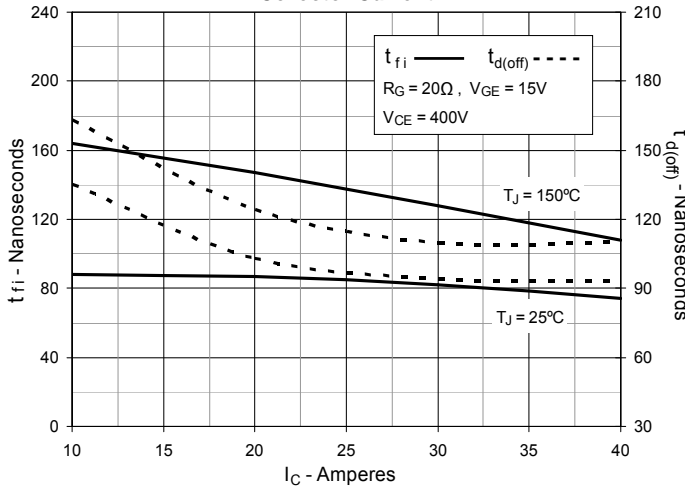
**Fig. 15. Inductive Switching Energy Loss vs. Junction Temperature**



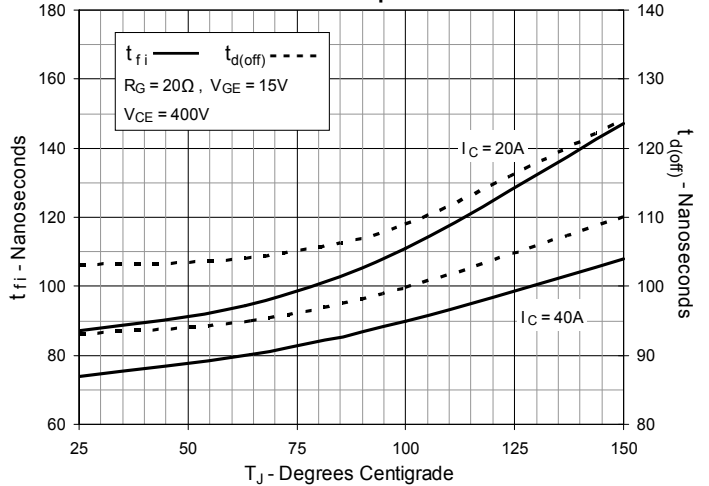
**Fig. 16. Inductive Turn-off Switching Times vs. Gate Resistance**



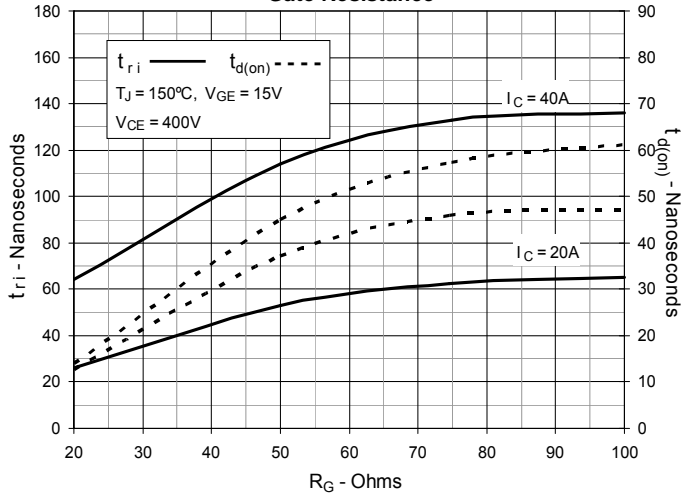
**Fig. 17. Inductive Turn-off Switching Times vs. Collector Current**



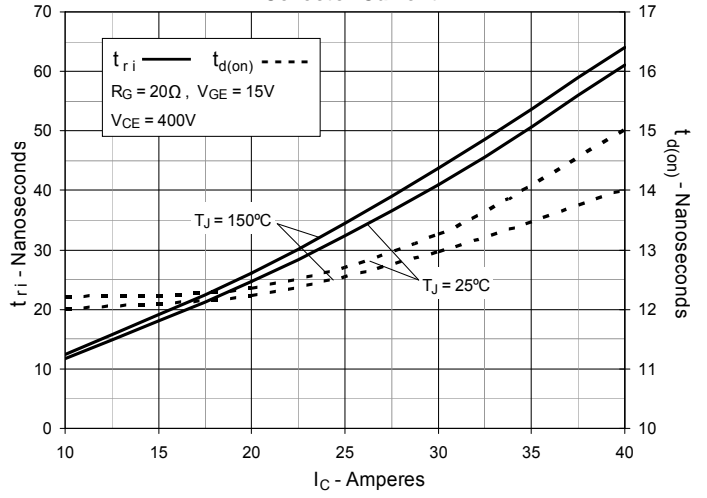
**Fig. 18. Inductive Turn-off Switching Times vs. Junction Temperature**



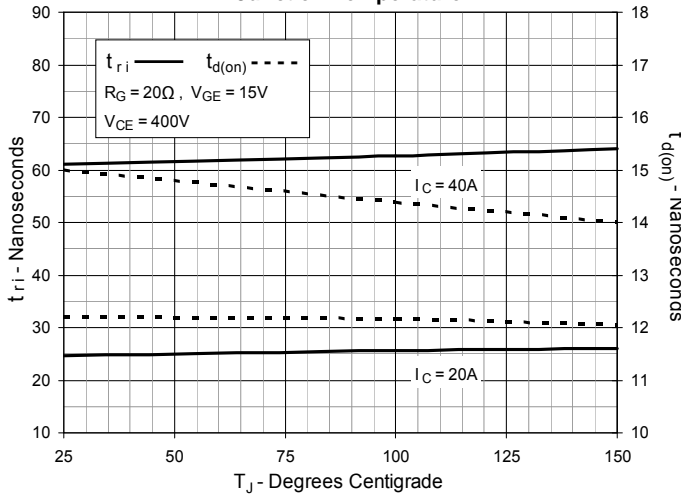
**Fig. 19. Inductive Turn-on Switching Times vs. Gate Resistance**



**Fig. 20. Inductive Turn-on Switching Times vs. Collector Current**



**Fig. 21. Inductive Turn-on Switching Times vs. Junction Temperature**





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[IDW40E65D2](#) [NGTB50N60L2WG](#) [STGB10H60DF](#) [STGB20V60F](#) [STGB40V60F](#) [STGFW80V60F](#) [IGW40N120H3FKSA1](#)  
[RJH60D7BDPQ-E0#T2](#) [APT40GR120B](#)